

20V NPN HIGH GAIN TRANSISTOR IN SOT223

Features

- $BV_{CEX} > 100V$
- $BV_{CEO} > 20V$
- BV_{ECO} > 6V
- I_C = 7A High Continuous Current
- Low Saturation Voltage V_{CE(sat)} < 48mV @ 1A
- $R_{CE(sat)} = 31m\Omega$
- Complementary PNP Type: ZXTP25020DG
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

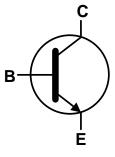
- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound;
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.112 grams (Approximate)

Applications

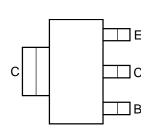
- DC-DC Converters
- Motor Drive
- Relay, Lamp and Solenoid Drive
- **Regulator Circuits**







Device Symbol



Top View Pin-Out

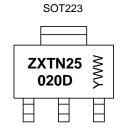
Ordering Information (Notes 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN25020DGTA	AEC-Q101	ZXTN25020D	7	12	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



ZXTN25020D = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W = \text{Week Code } (01~53)$



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	100	V
Collector-Emitter Voltage (forward blocking)	V _{CEX}	100	V
Collector-Emitter Voltage	V _{CEO}	20	V
Emitter-Collector Voltage (reverse blocking)	V _{ECO}	6	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ic	7	Α
Base Current	I _B	1	Α
Peak Pulse Current	I _{CM}	15	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		1.2 9.6		
Power Dissipation	(Note 6)	D	1.6 12.8	W mW/°C	
Linear Derating Factor	(Note 7)	P _D	3 24		
	(Note 8)		5.3 42		
	(Note 5)		104		
Thermal Desistance, Junction to Ambient	(Note 6)		78		
Thermal Resistance, Junction to Ambient	(Note 7)	R _{0JA}	42	°C/W	
	(Note 8)		23.5		
Thermal Resistance, Junction to Lead (Note 9)		R _{0JL}	16]	
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-55 to +150	°C		

ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С
Notes: 5. For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air				

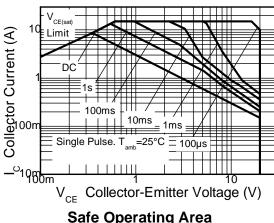
conditions whilst operating in steady-state.

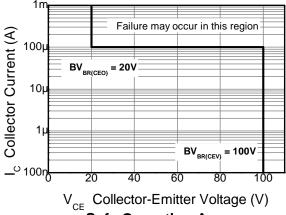
Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.

- Same as Note 5, except the device is mounted on 25mm x 25mm 102 copper.
 Same as Note 7 measured at t<5 seconds.
 Thermal resistance from junction to solder-point (at the end of the collector lead).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.

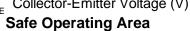


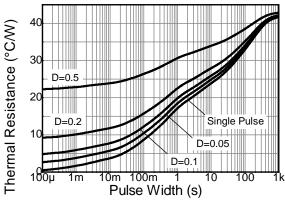
Thermal Characteristics and Derating Information (@T_A = +25°C, unless otherwise specified.)

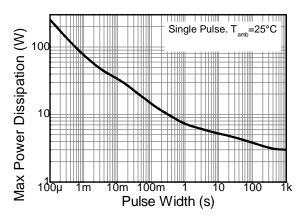




Safe Operating Area

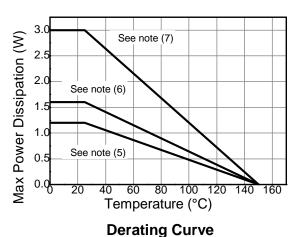






Transient Thermal Impedance

Pulse Power Dissipation





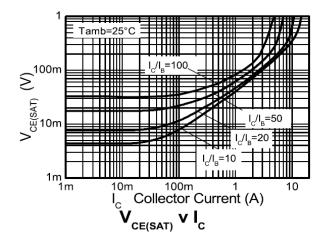
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

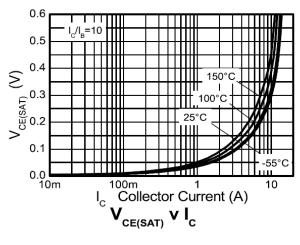
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	100	125	_	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (forward blocking)	BV _{CEX}	100	120	-	V	$I_C = 100\mu A$, $R_{BE} < 1k\Omega$ or $-1V < V_{BE} > 0.25V$
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	20	35	-	V	$I_C = 10mA$
Emitter-Collector Breakdown Voltage (reverse blocking)	BV _{ECX}	6	8.3	-	V	$I_E = 100\mu A$, $R_{BC} < 1k\Omega$ or $0.25V < V_{BC} > -0.25V$
Emitter-Collector Breakdown Voltage (reverse blocking)	BV _{ECO}	5	6.1	-	V	I _E = 100μA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.3	_	V	I _E = 100μA
Collector Cut-Off Current	1	_	< 1	50	nA	V _{CB} = 100V
Collector Cut-Oir Current	Ісво	_	_	0.5	μΑ	V _{CB} = 100V, T _A = 100°C
Collector-Emitter Cut-Off Current	I _{CEX}	_	-	100	nA	$V_{CE} = 100V, R_{BE} < 1k\Omega \text{ or}$ -1V < $V_{BE} > 0.25V$
Emitter Cut-Off Current	I _{EBO}	_	< 1	50	nA	V _{EB} = 5.6V
		_	40	48	mV	$I_C = 1A$, $I_B = 100mA$
		_	60	75	mV	$I_C = 1A$, $I_B = 20mA$
Collector-Emitter Saturation Voltage (Note 11)	$V_{CE(sat)}$	_	100	120	mV	$I_C = 2A$, $I_B = 40mA$
	, ,	_	130	180	mV	$I_C = 2A$, $I_B = 20mA$
		-	225	290	mV	$I_C = 7A$, $I_B = 700mA$
Base-Emitter Saturation Voltage (Note 11)	$V_{BE(sat)}$	-	1,090	1,150	mV	$I_C = 7A$, $I_B = 700mA$
Base-Emitter Turn-On Voltage (Note 11)	$V_{BE(on)}$	-	950	1,050	mV	$I_C = 7A$, $V_{CE} = 2V$
	h _{FE}	300	450	900	=	$I_C = 10$ mA, $V_{CE} = 2$ V
DC Current Gain (Note 11)		250	360	-	-	$I_C = 2A$, $V_{CE} = 2V$
DC Current Gain (Note 11)		50	85	-	-	$I_C = 7A$, $V_{CE} = 2V$
		-	15	-	-	$I_C = 15A, V_{CE} = 2V$
Current Gain-Bandwidth Product (Note 11)	f⊤	-	215	-	MHz	$V_{CE} = 10V, I_{C} = 50mA,$ f = 100MHz
Input Capacitance (Note 11)	C _{ibo}	_	152	_	pF	V _{EB} = 0.5V, f = 1MHz
Output Capacitance (Note 11)	C _{obo}	_	16.5	25	pF	V _{CB} = 10V, f = 1MHz
Delay Time	t _d	_	67.7		ns	
Rise Time	t _r	_	72.2	_	ns	$I_C = 1A, V_{CC} = 10V,$
Storage Time	t _s	_	361	-	ns	$I_{B1} = -I_{B2} = 10\text{mA}$
Fall Time	t _f	_	63.9	_	ns	

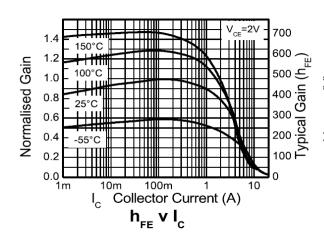
Note: 11. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

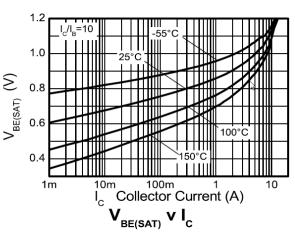


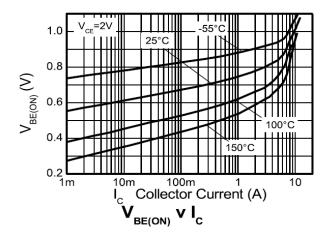
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)







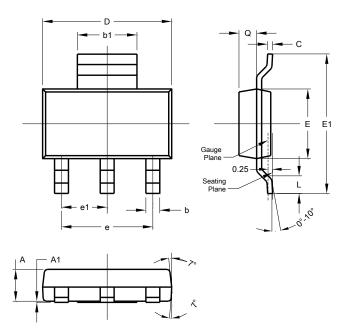






Package Outline Dimensions

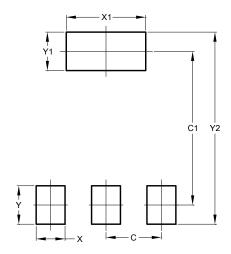
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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